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 INDICATION FORM**

Application Number	10/563,854
Filing Date	June 9, 2006
First Named Inventor	Eui Joon YOON
Title	Growth method for nitride semiconductor epitaxial layers
Art Unit	
Examiner Name	
Attorney Docket Number	504478.new

I hereby revoke all previous powers of attorney given in the above-identified application.

☐ A Power of Attorney is submitted herewith.

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☒ I hereby appoint Practitioner(s) associated with the following Customer Number as my/our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith:

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27128

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☐ Firm or Individual Name **Husch Blackwell Sanders LLP**

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I am the:

☐ Applicant/Inventor.

OR

☒ Assignee of record of the entire interest. See 37 CFR 3.71.

Statement under 37 CFR 3.73(b) (Form PTO/SB/96) submitted herewith or filed on

SIGNATURE of Applicant or Assignee of Record

Signature

Date

Name

Telephone

Title and Company

CEO of Seoul National University Industry Foundation

NOTE: Signatures of all the inventors or assignees of record of the entire interest or their representative(s) are required. Submit multiple forms if more than one signature is required, see below.

☒ Total of 1 forms are submitted.